

BIPOLAR TRANSISTOR, PNP, -260V, Transistor Polarity:PNP, Collector Emitter Voltage V(br)ceo:260V, Transition Frequency ft:30MHz, Power Dissipation Pd:200W, DC Collector Current:15A, DC Current Gain hFE:175hFE

Manufacturers	<u>ON Semiconductor, LLC</u>
Package/Case	TO-3PL
Product Type	Transistors
RoHS	Pb-free
Lifecycle	



Images are for reference only

Please submit RFQ for MJL1302AG or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

The MJL3281A and MJL1302A are power transistors for high power audio, disk head positioners and other linear applications.

Features

- Exceptional Safe Operating Area for reliable performance at higher powers
- NPN/PNP Gain Matching within 10% from 50mA to 5A for symmetrical
- Excellent Gain Linearity for accurate reproduction of input signal
- High VCE for greater dynamic range
- High frequency for high amplifier bandwidth

Application

ONSEMI



Related Products



[MJE172](#)

ON Semiconductor, LLC
TO-126



[MJD42CT4G](#)

ON Semiconductor, LLC
SOT25



[MJL21195G](#)

ON Semiconductor, LLC
TO-3PL



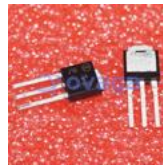
[MJ4502G](#)

ON Semiconductor, LLC
TO-204-2 (TO-3)



[MJE350G](#)

ON Semiconductor, LLC
TO-126



[MJD44H11-1G](#)

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TO-251



[MJ802G](#)

ON Semiconductor, LLC
TO-204-2



[MJH6287](#)

ON Semiconductor, LLC
TO-247